# NSN 5962-00-434-3150

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View Online at https://aerobasegroup.com/nsn/5962-00-434-3150 **Body Outside Diameter:** 0.556 inches **Body Height:** Between 0.049 inches and 0.068 inches **Maximum Power Dissipation Rating:** 150.0 milliwatts **Operating Tempurature Range:** -55.0/+125.0 degrees celsius Storage Tempurature Range: -65.0/+150.0 degrees celsius **Features Provided:** Hermetically sealed and monolithic and negative outputs and positive outputs **Inclosure Material:** Glass and metal **Inclosure Configuration:** Flat pack **Output Logic Form:** P-type metal oxide-semiconductor logic **Input Circuit Pattern:** 1 input **Terminal Surface Treatment:** Solder Voltage Rating And Type Per Characteristic: 0.3 volts power source **Time Rating Per Chacteristic:** 80.00 nanoseconds propagation delay time, low to high level output and 80.00 nanoseconds propagation delay time, high to low level output **Memory Device Type:** Rom

#### **Precious Material And Location:**

Body and terminal surfaces gold

**Precious Material:** 

Gold

### **Test Data Document:**

13499-351-8044 drawing (this is the basic governing drawing, such as a contractor drawing, original equipment manufacturer drawing, etc.; excludes any specification, standard or other document that may be referenced in a basic governing drawing)

## **Terminal Type And Quantity:**

34 flat leads

Shelf Life:

N/a

**Unit Of Measure:** 

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#### **Demilitarization:**

Yes - demil/mli

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